Silicon Schottky Barrier Diode for Various Detector, High Speed Switching

# HITACHI

ADE-208-153A (Z)

Rev. 1 Oct. 1998

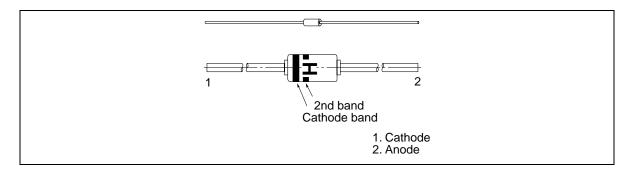
#### Features

- Detection efficiency is very good.
- Small temperature coefficient.
- High reliability with glass seal.

### **Ordering Information**

| Type No. | Cathode | 2nd band | Mark | Package Code |
|----------|---------|----------|------|--------------|
| 1SS106   | White   | White    | Н    | DO-35        |

#### Outline





# **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

| Item                      | Symbol         | Value       | Unit |
|---------------------------|----------------|-------------|------|
| Reverse voltage           | V <sub>R</sub> | 10          | V    |
| Average rectified current | I <sub>o</sub> | 30          | mA   |
| Junction temperature      | Тј             | 125         | °C   |
| Storage temperature       | Tstg           | –55 to +125 | °C   |

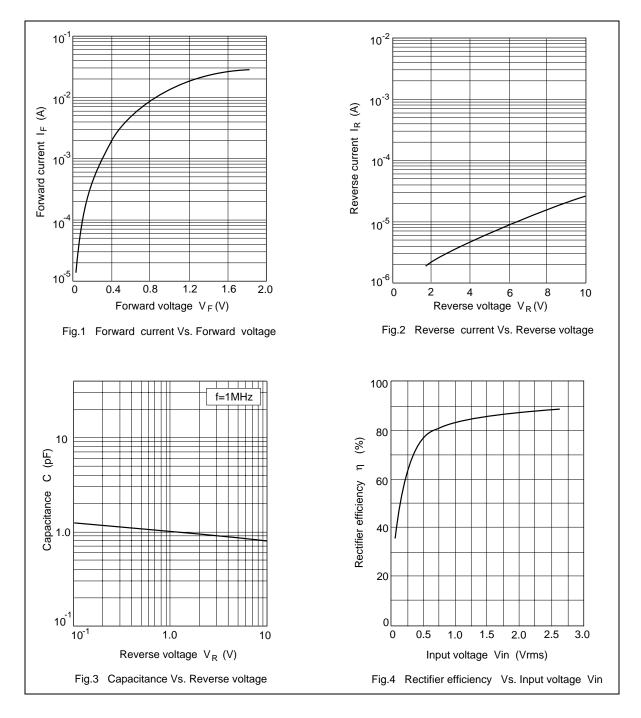
### **Electrical Characteristics**

 $(Ta = 25^{\circ}C)$ 

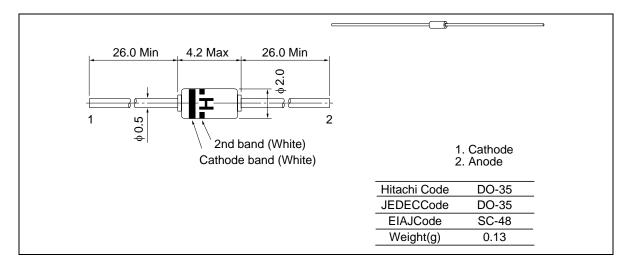
| Item                         | Symbol         | Min | Тур | Max | Unit | Test Condition   |
|------------------------------|----------------|-----|-----|-----|------|--|
| Forward current              | I <sub>F</sub> | 4.5 | _   | _   | mA   | $V_{\rm F} = 1V$   |
| Reverse current              | I <sub>R</sub> | _   | _   | 70  | μA   | V <sub>R</sub> = 6V  |
| Capacitance                  | С              | _   | _   | 1.5 | pF   | $V_{R} = 1V, f = 1MHz$                                     |
| Rectifier efficiency         | η              | 70  | —   | _   | %    | Vin = 2Vrms, f = 40MHz, $R_L = 5k\Omega$ ,<br>$C_L = 20pF$ |
| ESD-Capability <sup>*1</sup> | _              | 100 | —   | _   | V    | C = 200pF, Both forward and reverse direction 1 pulse.     |

Notes: 1. Failure criterion;  $I_{_R} \ge 140 \mu A$  at  $V_{_R} = 6V$ 

### **Main Characteristic**



# **Package Dimensions**



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